NSN 5962-01-161-3477

Memory Microcircuit - Page 1 of 2



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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0	.310 inches
Body Height:	
Between 0.140 inches and 0	.185 inches
Maximum Power Dissipatio	on Rating:
739.0 milliwatts	
Operating Tempurature Ra	nge:
-55.0/+125.0 degrees celsius	5
Storage Tempurature Rang	Je:
-65.0/+150.0 degrees celsius	
End Application:	
Radar system, type an/fps-1 ⁻	17
Features Provided:	
Hermetically sealed and mor	nolithic and high impedance and 3-state output and programmable and bipolar
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Case Outline Source And D	Designator:
D-2 mil-m-38510	
Terminal Surface Treatmen	ıt:
Solder	
Voltage Rating And Type P	er Characteristic:
5.5 volts power source	
Time Rating Per Chacterist	ic:
75.00 nanoseconds propaga	ation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Quantit	y:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

NSN 5962-01-161-3477

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

